

<b>Notice of References Cited</b>		Application No. <u>871742</u>		Applicant(s) <u>Zhang et al.</u>	
		08/462,742			
Examiner <b>Leon Radomsky</b>		Group Art Unit <b>1104</b>		Page 1 of 1	

  

U.S. PATENT DOCUMENTS					
DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	
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FOREIGN PATENT DOCUMENTS					
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